PDTC144W series

FEATURES

- Built-in bias resistors
- · Simplified circuit design
- Reduction of component count
- Reduced pick and place costs.

APPLICATIONS

- · General purpose switching and amplification
- · Inverter and interface circuits
- · Circuit driver.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V _{CEO}	collector-emitter voltage	_	50	V
Io	output current (DC)	_	100	mA
R1	bias resistor	47	_	kΩ
R2	bias resistor	22	_	kΩ

DESCRIPTION

NPN resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

PRODUCT OVERVIEW

TYPE NUMBER	PAC	KAGE	MARKING CODE	DND COMPLEMENT
I TPE NUMBER	PHILIPS	EIAJ	WARKING CODE	PNP COMPLEMENT
PDTC144WE	SOT416	SC-75	42	PDTA144WE
PDTC144WEF	SOT490	SC-89	34	PDTA144WEF
PDTC144WK	SOT346	SC-59	41	PDTA144WK
PDTC144WM	SOT883	SC-101	DD	PDTA144WM
PDTC144WS	SOT54 (TO-92)	SC-43	TC144W	PDTA144WS
PDTC144WT	SOT23	_	*20 ⁽¹⁾	PDTA144WT
PDTC144WU	SOT323	SC-70	*20(1)	PDTA144WU

Note

- 1. * = p: Made in Hong Kong.
 - * = t: Made in Malaysia.
 - * = W: Made in China.

NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTC144W series

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	CIMPLIFIED OUTLINE AND CYMPOL		PINNING
TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PIN	DESCRIPTION
PDTC144WS	1 R1 R2	1 2 3	base collector emitter
PDTC144WE PDTC144WEF PDTC144WK PDTC144WT PDTC144WU	3 1 R1 R2 2 Top view MDB269	1 2 3	base emitter collector
PDTC144WM	2 1 R1 3 Bottom view MHC506	1 2 3	base emitter collector

NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTC144W series

ORDERING INFORMATION

TYPE NUMBER		PACKAGE	
I TPE NUMBER	NAME	DESCRIPTION	VERSION
PDTC144WE	_	plastic surface mounted package; 3 leads	SOT416
PDTC144WEF	_	plastic surface mounted package; 3 leads	SOT490
PDTC144WK	_	plastic surface mounted package; 3 leads	SOT346
PDTC144WM	_	leadless ultra small plastic package; 3 solder lands; body $1.0 \times 0.6 \times 0.5 \text{ mm}$	SOT883
PDTC144WS	_	plastic single-ended leaded (through hole) package; 3 leads	SOT54
PDTC144WT	_	plastic surface mounted package; 3 leads	SOT23
PDTC144WU	_	plastic surface mounted package; 3 leads	SOT323

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	50	V
V _{CEO}	collector-emitter voltage	open base	_	50	V
V _{EBO}	emitter-base voltage	open collector	_	10	V
Vi	input voltage				
	positive		_	+40	V
	negative		_	-10	V
Io	output current (DC)		_	100	mA
I _{CM}	peak collector current		_	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C			
	SOT54	note 1	_	500	mW
	SOT23	note 1	_	250	mW
	SOT346	note 1	_	250	mW
	SOT323	note 1	_	200	mW
	SOT490	notes 1 and 2	_	250	mW
	SOT883	notes 2 and 3	_	250	mW
	SOT416	note 1	_	150	mW
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μm copper strip line.

NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTC144W series

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT490	notes 1 and 2	500	K/W
	SOT883	notes 2 and 3	500	K/W
	SOT416	note 1	833	K/W

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μm copper strip line.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	V _{CB} = 50 V; I _E = 0 A	_	_	100	nA
I _{CEO}	collector-emitter cut-off current	V _{CE} = 30 V; I _B = 0 A	_	_	1	μΑ
		$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}; T_{j} = 150 ^{\circ}\text{C}$	_	_	50	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A	_	_	110	μΑ
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$	60	_	_	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	_	_	150	mV
V _{i(off)}	input-off voltage	$I_C = 100 \mu\text{A}; V_{CE} = 5 \text{V}$	_	1.7	1.2	V
V _{i(on)}	input-on voltage	$I_C = 2 \text{ mA}; V_{CE} = 0.3 \text{ V}$	4	2.7	_	V
R1	input resistor		33	47	61	kΩ
R2 R1	resistor ratio		0.37	0.47	0.57	
C _c	collector capacitance	I _E = i _e = 0 A; V _{CB} = 10 V; f = 1 MHz	_	_	2.5	pF

NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTC144W series

PACKAGE OUTLINES

Plastic surface mounted package; 3 leads

0.30

0.15

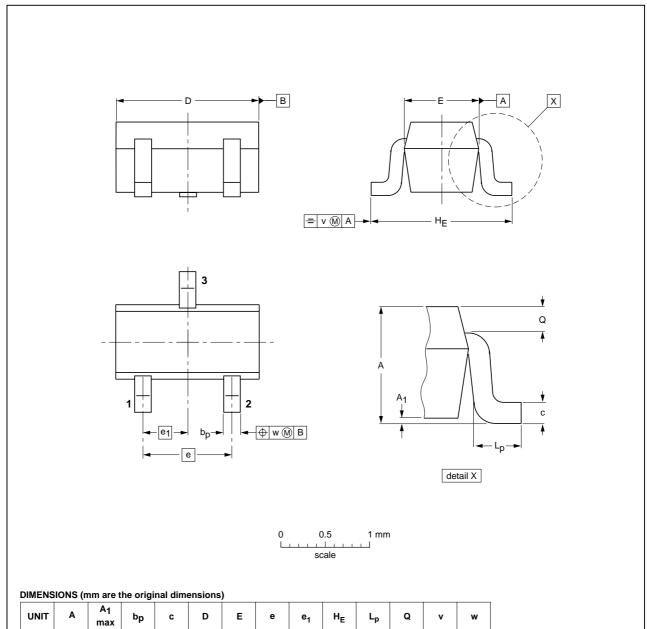
0.1

0.25

0.10

1.8

SOT416



OUTLINE		REFER	REFERENCES		EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT416			SC-75			97-02-28	

1.75

1.45

1

0.5

0.45

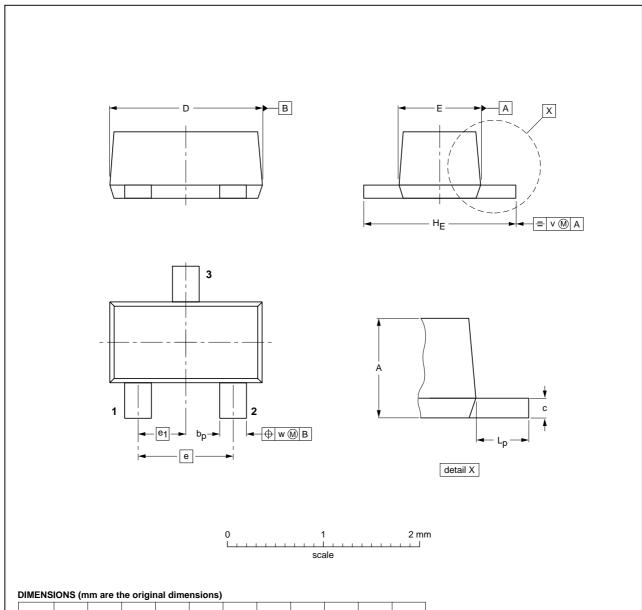
0.23

0.2

PDTC144W series

Plastic surface mounted package; 3 leads

SOT490



UNIT	A	bp	С	D	E	е	e ₁	HE	Lp	v	w
mm	0.8 0.6	0.33 0.23	0.2 0.1	1.7 1.5	0.95 0.75	1.0	0.5	1.7 1.5	0.5 0.3	0.1	0.1

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT490			SC-89		98-10-23	

PDTC144W series

Plastic surface mounted package; 3 leads

1.3

1.0

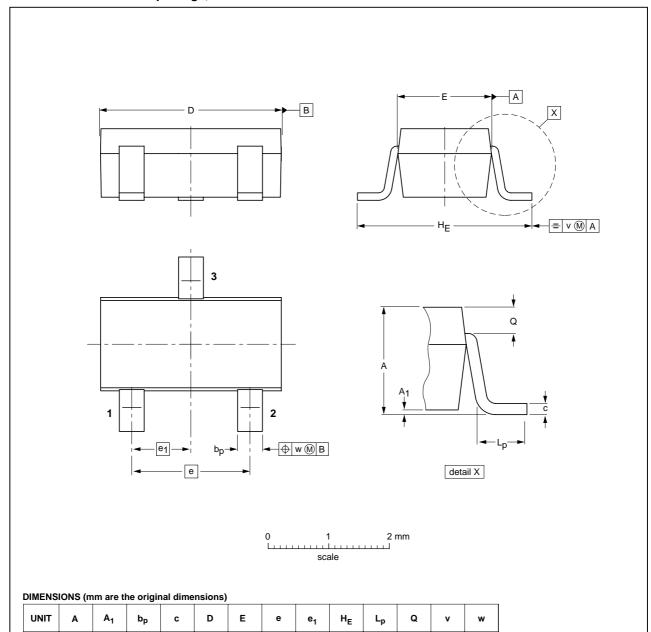
0.1

0.013

0.50

0.35

SOT346



OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT346		TO-236	SC-59		$\bigoplus \bigoplus$	98-07-17	

0.95

1.9

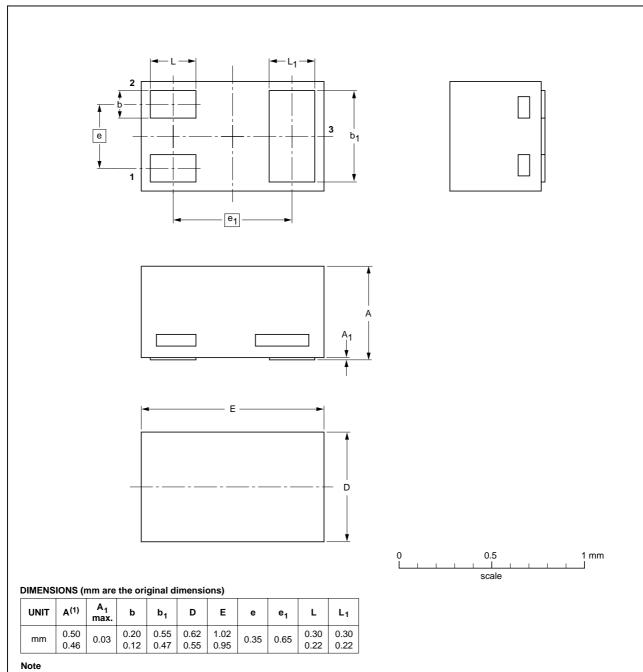
0.33

0.2

PDTC144W series

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883



1. Including plating thickness

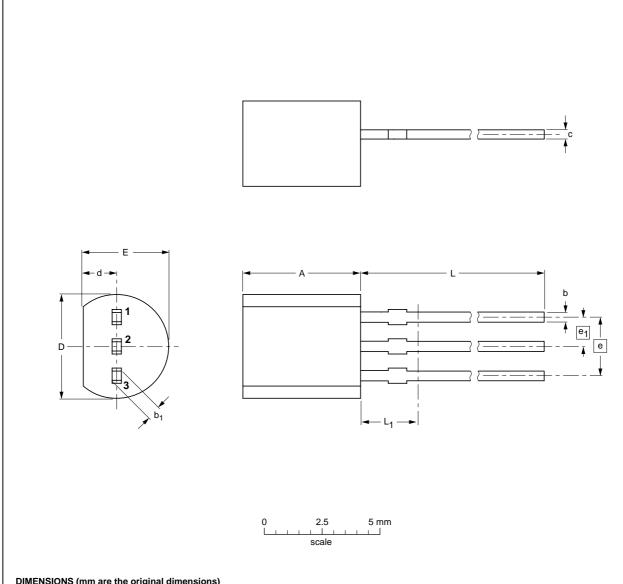
OUTLINE		REFER	ENCES		EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT883			SC-101			03-02-05 03-04-03	

NPN resistor-equipped transistors; $R1 = 47 \text{ k}\Omega$, $R2 = 22 \text{ k}\Omega$

PDTC144W series

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b ₁	С	D	d	E	е	e ₁	L	L ₁ ⁽¹⁾ max.	
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5	

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE	REFERENCES				EUROPEAN	IOOUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT54		TO-92	SC-43A			97-02-28 04-06-28

PDTC144W series

Plastic surface mounted package; 3 leads

0.48

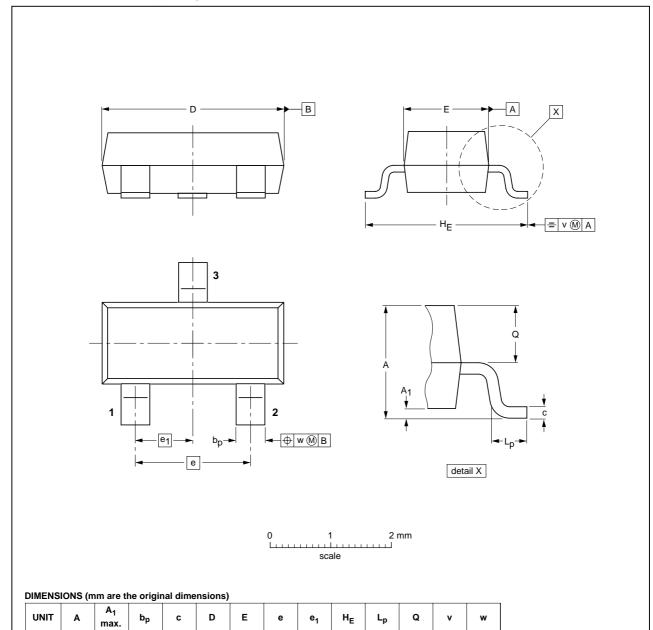
0.38

0.1

0.9

mm

SOT23



OUTLINE	REFERENCES EUROPEAN				ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT23		TO-236AB				97-02-28 99-09-13

0.95

1.9

0.45

0.55

0.2

NPN resistor-equipped transistors; $R1 = 47 \text{ k}\Omega$, $R2 = 22 \text{ k}\Omega$

PDTC144W series

Plastic surface mounted package; 3 leads

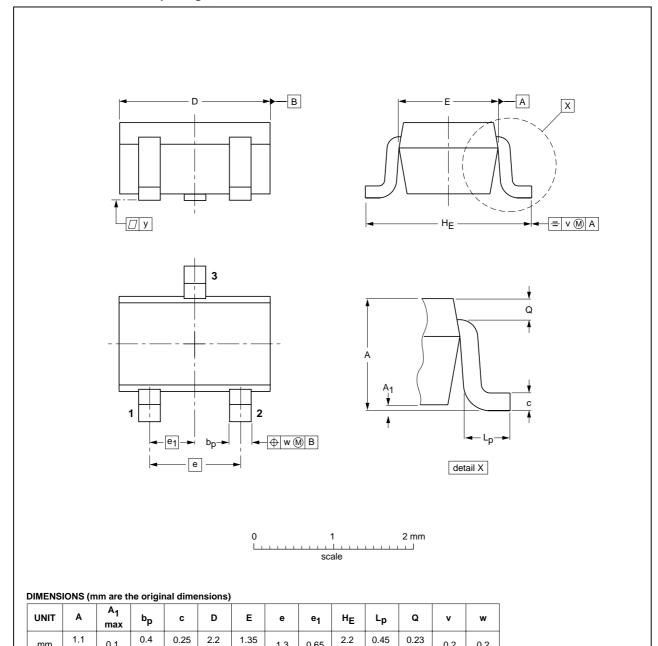
0.1

0.3

0.10

mm

SOT323



OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT323			SC-70			97-02-28

0.2

0.2

0.65

NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTC144W series

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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